

# Unidirectional quadruple ESD protection diode arrays Rev. 01 — 17 January 2008 Product delignment of the control of the cont

Product data sheet

### **Product profile**

#### 1.1 General description

Unidirectional quadruple ElectroStatic Discharge (ESD) protection diode arrays in a small SOT886 Surface-Mounted Device (SMD) plastic package designed to protect up to four signal lines from the damage caused by ESD and other transients.

#### 1.2 Features

- ESD protection of up to four lines
- Max. peak pulse power: P<sub>PP</sub> = 110 W
- Low clamping voltage: V<sub>CL</sub> = 11 V
- Ultra low leakage current: I<sub>RM</sub> = 4 nA
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); I<sub>PP</sub> = 10 A
- AEC-Q101 qualified

#### 1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Communication systems
- Portable electronics

#### 1.4 Quick reference data

Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

| Symbol    | Parameter                | Conditions             | Min | Тур | Max | Unit |
|-----------|--------------------------|------------------------|-----|-----|-----|------|
| Per diode | )                        |                        |     |     |     |      |
| $V_{RWM}$ | reverse standoff voltage |                        |     |     |     |      |
|           | PESD3V3S4UF              |                        | -   | -   | 3.3 | V    |
|           | PESD5V0S4UF              |                        | -   | -   | 5.0 | V    |
| $C_d$     | diode capacitance        | $f = 1 MHz; V_R = 0 V$ |     |     |     |      |
|           | PESD3V3S4UF              |                        | -   | 110 | 300 | pF   |
|           | PESD5V0S4UF              |                        | -   | 85  | 220 | pF   |



Unidirectional quadruple ESD protection diode arrays

### 2. Pinning information

Table 2. Pinning

| I GIOTO E. | 9                 |                    |                                |
|------------|-------------------|--------------------|--------------------------------|
| Pin        | Description       | Simplified outline | Symbol                         |
| 1          | cathode (diode 1) |                    |                                |
| 2          | common anode      | 1 2 3              | 1 <del>  [   •   ]    </del> 6 |
| 3          | cathode (diode 2) |                    | 2 5                            |
| 4          | cathode (diode 3) |                    | 3 1 1 4                        |
| 5          | common anode      | 6 5 4              | 006aaa156                      |
| 6          | cathode (diode 4) | bottom view        |                                |

### 3. Ordering information

Table 3. Ordering information

| Type number | Package |   |         |
|-------------|---------|---|---------|
|             | Name    | Description   | Version |
| PESD3V3S4UF | XSON6   | plastic extremely thin small outline package;             | SOT886  |
| PESD5V0S4UF |         | no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm |         |

### 4. Marking

Table 4. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PESD3V3S4UF | A3                          |
| PESD5V0S4UF | A4                          |

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol          | Parameter          | Conditions           | Min    | Max | Unit |
|-----------------|--------------------|----------------------|--------|-----|------|
| Per diode       |                    |                      |        |     |      |
| P <sub>PP</sub> | peak pulse power   | $t_p = 8/20 \ \mu s$ | [1][2] | 110 | W    |
| I <sub>PP</sub> | peak pulse current | $t_p = 8/20 \ \mu s$ | [1][2] | 10  | Α    |

#### Unidirectional quadruple ESD protection diode arrays

 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| Per device       |                      |            |     |      |      |
| Tj               | junction temperature |            | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature  |            | -55 | +150 | °C   |
| $T_{stg}$        | storage temperature  |            | -65 | +150 | °C   |

- [1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.
- [2] Measured from pin 1, 3, 4 or 6 to pin 2 or 5.

Table 6. ESD maximum ratings

T<sub>amb</sub> = 25 °C unless otherwise specified.

| Symbol   | Parameter                            | Conditions                     |   | Min | Max | Unit |
|--|--------------------------------------|--------------------------------|---|-----|-----|------|
| Per diode  |                                      |                                |   |     |     |      |
| V <sub>ESD</sub> electrostatic discharge voltage | IEC 61000-4-2<br>(contact discharge) | [1][2]                         | - | 30  | kV  |      |
|  |                                      | MIL-STD-883 (human body model) |   | -   | 10  | kV   |

- [1] Device stressed with ten non-repetitive ESD pulses.
- [2] Measured from pin 1, 3, 4 or 6 to pin 2 or 5.

Table 7. ESD standards compliance

| Standard                                | Conditions                      |
|---|---------------------------------|
| Per diode                               |                                 |
| IEC 61000-4-2; level 4 (ESD)            | > 15 kV (air); > 8 kV (contact) |
| MIL-STD-883; class 3 (human body model) | > 4 kV                          |

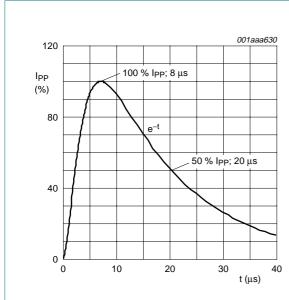


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5

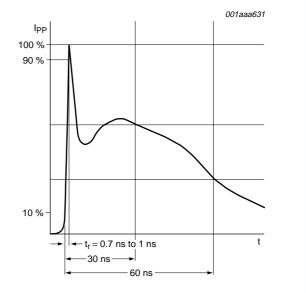


Fig 2. ESD pulse waveform according to IEC 61000-4-2

PESD3V3S4UF\_PESD5V0S4UF\_1

© Nexperia B.V. 2017. All rights reserved

Unidirectional quadruple ESD protection diode arrays

### 6. Characteristics

Table 8. Characteristics

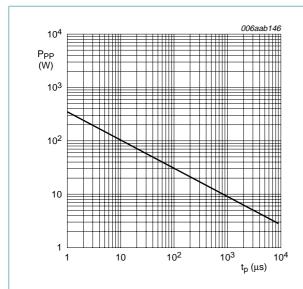
T<sub>amb</sub> = 25 °C unless otherwise specified.

| Symbol           | Parameter                | Conditions              | ı      | Min  | Тур | Max  | Unit |
|------------------|--------------------------|-------------------------|--------|------|-----|------|------|
| Per diod         | le                       |                         |        |      |     |      |      |
| $V_{RWM}$        | reverse standoff voltage |                         |        |      |     |      |      |
|                  | PESD3V3S4UF              |                         | -      | •    | -   | 3.3  | V    |
|                  | PESD5V0S4UF              |                         | -      | •    | -   | 5.0  | V    |
| I <sub>R</sub>   | reverse current          |                         |        |      |     |      |      |
|                  | PESD3V3S4UF              | $V_R = 3.0 \text{ V}$   |        | •    | 100 | 1000 | nΑ   |
|                  | PESD5V0S4UF              | $V_{R} = 4.3 \text{ V}$ | -      | •    | 4   | 100  | nΑ   |
| $V_{BR}$         | breakdown voltage        | $I_R = 1 \text{ mA}$    |        |      |     |      |      |
|                  | PESD3V3S4UF              |                         |        | 5.32 | 5.6 | 5.88 | V    |
|                  | PESD5V0S4UF              |                         | (      | 5.46 | 6.8 | 7.14 | V    |
| C <sub>d</sub>   | diode capacitance        | $f = 1 MHz; V_R = 0 V$  |        |      |     |      |      |
|                  | PESD3V3S4UF              |                         |        |      | 110 | 300  | pF   |
|                  | PESD5V0S4UF              |                         |        |      | 85  | 220  | pF   |
| $V_{CL}$         | clamping voltage         |                         | [1][2] |      |     |      |      |
|                  | PESD3V3S4UF              | I <sub>PP</sub> = 1 A   | -      |      | -   | 8    | V    |
|                  |                          | I <sub>PP</sub> = 10 A  | -      |      | -   | 11   | V    |
|                  | PESD5V0S4UF              | I <sub>PP</sub> = 1 A   |        | •    | -   | 8    | V    |
|                  |                          | I <sub>PP</sub> = 10 A  | -      | •    | -   | 12   | V    |
| r <sub>dif</sub> | differential resistance  | $I_R = 1 \text{ mA}$    |        |      |     |      |      |
|                  | PESD3V3S4UF              |                         | -      | •    | -   | 400  | Ω    |
|                  | PESD5V0S4UF              |                         | -      | •    | -   | 200  | Ω    |

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

<sup>[2]</sup> Measured from pin 1, 3, 4 or 6 to pin 2 or 5.

Unidirectional quadruple ESD protection diode arrays



 $T_{amb} = 25 \, ^{\circ}C$ 

Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

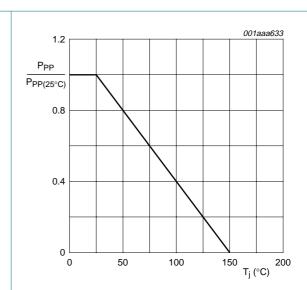
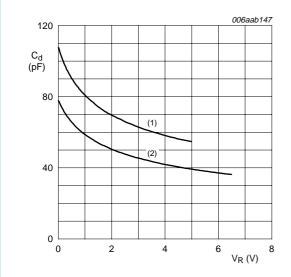


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ 

- (1) PESD3V3S4UF
- (2) PESD5V0S4UF

Fig 5. Diode capacitance as a function of reverse voltage; typical values

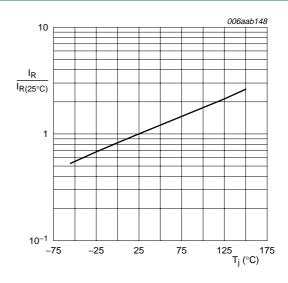
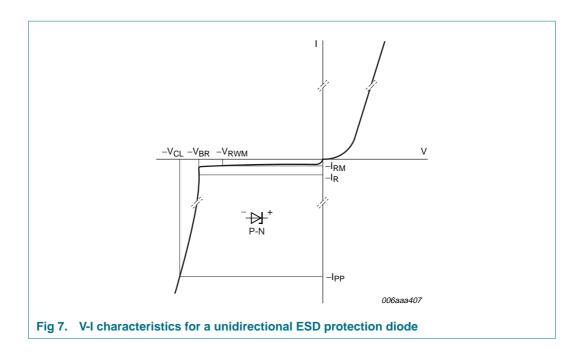


Fig 6. Relative variation of reverse current as a function of junction temperature; typical values

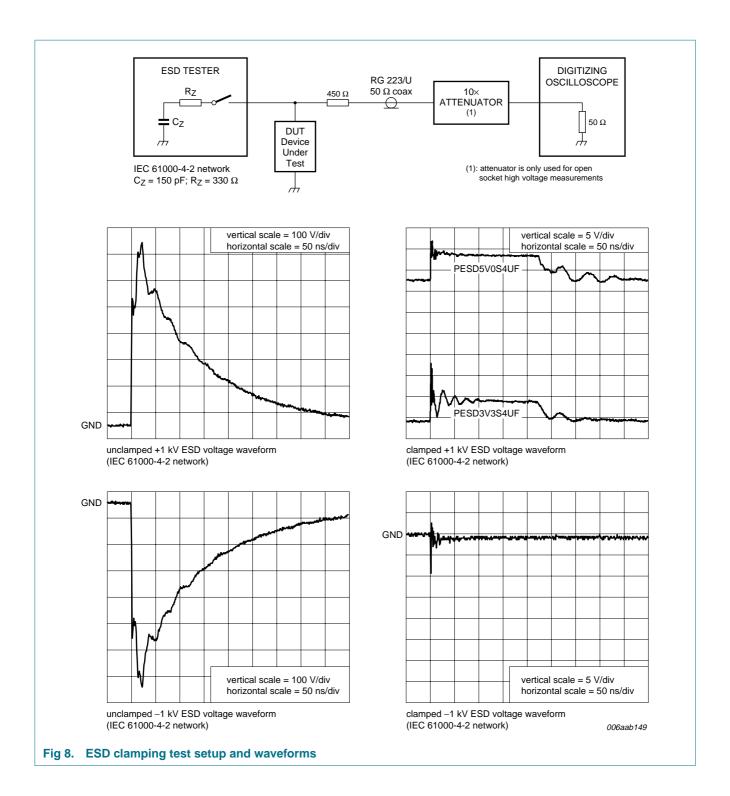
#### Unidirectional quadruple ESD protection diode arrays



**Product data sheet** 

6 of 13

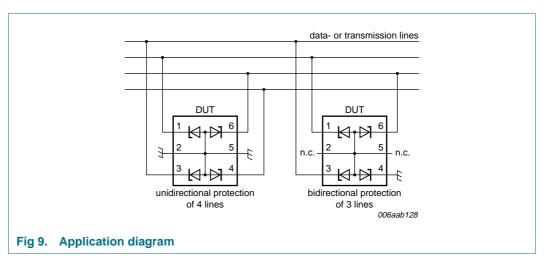
Unidirectional quadruple ESD protection diode arrays



Unidirectional quadruple ESD protection diode arrays

### 7. Application information

The PESDxS4UF is designed for the protection of up to four unidirectional data or signal lines from the damage caused by ESD and surge pulses. The PESDxS4UF may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESDxS4UF provides a surge capability of 110 W per line for an 8/20  $\mu$ s waveform each.



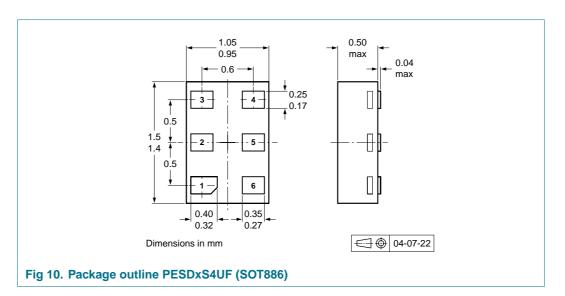
#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESDxS4UF as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

Unidirectional quadruple ESD protection diode arrays

#### **Package outline** 8.



#### **Packing information** 9.

Table 9. **Packing methods** 

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                        | Packing quantity |
|-------------|---------|------------------------------------|------------------|
|             |         |                                    | 5000             |
| PESD3V3S4UF | SOT886  | 4 mm pitch, 8 mm tape and reel; T1 | 2 -115           |
|             |         | 4 mm pitch, 8 mm tape and reel; T4 | 3 -132           |
| PESD5V0S4UF | SOT886  | 4 mm pitch, 8 mm tape and reel; T1 | 2 -115           |
|             |         | 4 mm pitch, 8 mm tape and reel; T4 | 3 -132           |

[1] For further information and the availability of packing methods, see Section 13.

[2] T1: normal taping

[3] T4: 90° rotated reverse taping

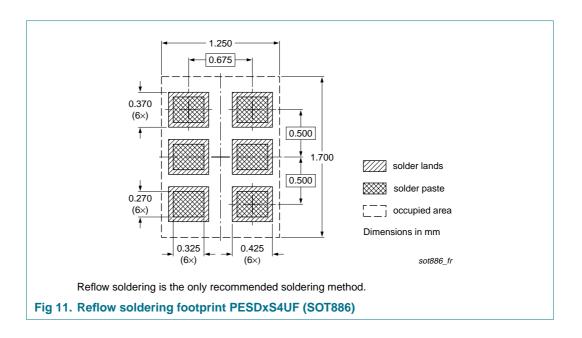
PESD3V3S4UF\_PESD5V0S4UF\_1

**Product data sheet** 

9 of 13

Unidirectional quadruple ESD protection diode arrays

### 10. Soldering



**Product data sheet** 

10 of 13

Unidirectional quadruple ESD protection diode arrays

# 11. Revision history

#### Table 10. Revision history

| Document ID               | Release date | Data sheet status  | Change notice | Supersedes |
|---------------------------|--------------|--------------------|---------------|------------|
| PESD3V3S4UF_PESD5V0S4UF_1 | 20080117     | Product data sheet | -             | -          |

PESD3V3S4UF\_PESD5V0S4UF\_1 © Nexperia B.V. 2017. All rights reserved

**Product data sheet** 

Unidirectional quadruple ESD protection diode arrays

#### 12. Legal information

#### 12.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nexperia.com">http://www.nexperia.com</a>.

#### 12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

#### 12.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — Nexperia products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia accepts no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by Nexperia. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 13. Contact information

For additional information, please visit: http://www.nexperia.com

For sales office addresses, send an email to: salesaddresses@nexperia.com

### **Nexperia**

Unidirectional quadruple ESD protection diode arrays

### 14. Contents

| 1    | Product profile         |
|------|-------------------------|
| 1.1  | General description     |
| 1.2  | Features                |
| 1.3  | Applications            |
| 1.4  | Quick reference data1   |
| 2    | Pinning information     |
| 3    | Ordering information    |
| 4    | Marking 2               |
| 5    | Limiting values         |
| 6    | Characteristics4        |
| 7    | Application information |
| 8    | Package outline         |
| 9    | Packing information     |
| 10   | Soldering 10            |
| 11   | Revision history        |
| 12   | Legal information       |
| 12.1 | Data sheet status       |
| 12.2 | Definitions             |
| 12.3 | Disclaimers             |
| 12.4 | Trademarks              |
| 13   | Contact information     |
| 11   | Contents                |

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 17 January 2008

<sup>©</sup> Nexperia B.V. 2017. All rights reserved